

# Data Sheet

### July 1999 File Number 4624.1

# Radiation Hardened Dual JK Flip Flop

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Intersil's Satellite Applications Flow<sup>TM</sup> (SAF) devices are fully tested and guaranteed to 100kRAD total dose. These QML Class T devices are processed to a standard flow intended to meet the cost and shorter lead-time needs of large volume satellite manufacturers, while maintaining a high level of reliability.

The Intersil HCTS109T is a Radiation Hardened Dual JK Flip Flop with set and reset. The flip flop changes state with the positive transition of the clock (CP1 or CP2).

# Specifications

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.

Detailed Electrical Specifications for the HCTS109T are contained in SMD 5962-95769. A "hot-link" is provided from our website for downloading.

www.intersil.com/spacedefense/newsafclasst.asp

Intersil's Quality Management Plan (QM Plan), listing all Class T screening operations, is also available on our website.

www.intersil.com/quality/manuals.asp

# Ordering Information

ORDERING NUMBER	PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)
5962R9576901TEC	HCTS109DTR	-55 to 125
5962R9576901TXC	HCTS109KTR	-55 to 125

NOTE: Minimum order quantity for -T is 150 units through distribution, or 450 units direct.

# Features

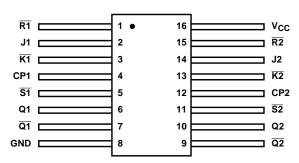
- QML Class T, Per MIL-PRF-38535
- Radiation Performance
  - Gamma Dose (γ) 1 x 10<sup>5</sup> RAD(Si)
  - Latch-Up Free Under Any Conditions
  - SEP Effective LET No Upsets: >100 MEV-cm<sup>2</sup>/mg
  - Single Event Upset (SEU) Immunity < 2 x 10<sup>-9</sup> Errors/Bit-Day (Typ)
- 3 Micron Radiation Hardened SOS CMOS
- Significant Power Reduction Compared to LSTTL ICs
- DC Operating Voltage Range: 4.5V to 5.5V
- LSTTL Input Logic Compatibility
  - V<sub>IL</sub> = 0.8V Max
  - $V_{IH} = V_{CC/2}$  Min
- Input Current Levels Ii ≤ 5mA at V<sub>OL</sub>, V<sub>OH</sub>

#### Pinouts

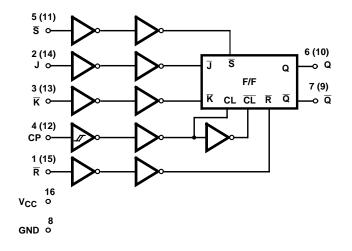
HCTS109T (SBDIP), CDIP2-T16 TOP VIEW

RI	1	,	 16	v <sub>cc</sub>
J1	2		15	<b>R2</b>
<u>K1</u>	3		14	J2
CP1	4		13	K2
<b>S1</b>	5		12	CP2
Q1	6		11	<u>S2</u>
<b>Q1</b>	7		10	Q2
GND	8		9	Q2

#### HCTS109T (FLATPACK), CDFP4-F16 TOP VIEW



# Functional Diagram



#### TRUTH TABLE

INPUTS				OUTPUTS		
S	R	СР	J	ĸ	Q	Q
L	Н	Х	Х	Х	Н	L
н	L	Х	Х	Х	L	Н
L	L	Х	Х	Х	H†	Η†
н	Н		L	L	L	Н
н	Н		Н	L	Toggle	
н	Н		L	Н	No Change	
н	Н		н	Н	Н	L
н	Н	L	Х	Х	No Change	

 $\dagger$  Unpredictable and unstable condition if both  $\overline{S}$  and  $\overline{R}$  go high simultaneously.

# **Die Characteristics**

### DIE DIMENSIONS:

2261μm x 2235μm x 533μm ±51μm) 89 x 88 x 21mils ±2mil

#### **METALLIZATION:**

Type: Al Si Thickness: 11kÅ 1kÅ

#### SUBSTRATE POTENTIAL:

Unbiased Silicon on Sapphire

### BACKSIDE FINISH:

Sapphire

# Metallization Mask Layout

# PASSIVATION:

Type: Silox (S<sub>i</sub>O<sub>2</sub>) Thickness: 13kÅ ±2.6kÅ

# WORST CASE CURRENT DENSITY:

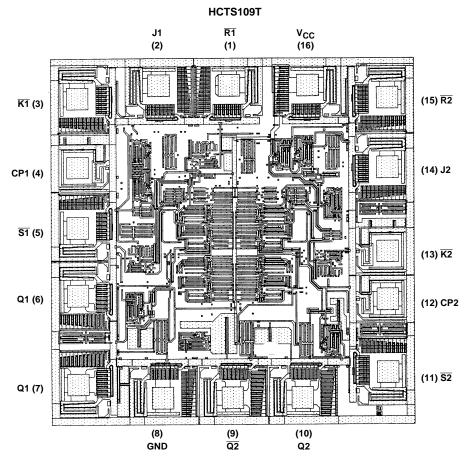
< 2.0e5 A/cm<sup>2</sup>

### TRANSISTOR COUNT:

268

# PROCESS:

CMOS SOS



NOTE: The die diagram is a generic plot form a similar HCS device. It is intended to indicate approximate die size and bond pad location. The mask series for the HCTS109 is TA14440A.

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